# MA4FCP300

# MACOM Silicon Flip Chip PIN Diode

### **Features**

Low Series Resistance : 2.6 Ω
 Low Capacitance : 45 fF
 Fast Switching Speed : 40 nS
 Silicon Nitride Passivation

Polyimide Scratch Protection

■ Designed for Automated Pick and Place Insertion

Rugged by Design

### **Description**

M/A-COM's MA4FCP Series consists of Silicon Flip Chip PIN diodes fabricated with M/A-COM's patented HMIC process. This diode is fabricated on epitaxial wafers using a process designed for repeatable electrical characteristics and extremely low parasitics. This diode is fully passivated with Silicon Nitride and has an additional layer of Polyimide for scratch protection. These protective coatings prevent damage to the junction during automated or manual handling. This flip chip configuration is suitable for pick and place insertion.

### **Applications**

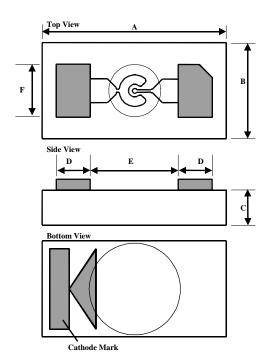
The small 0315 outline and low 0.12 pS RC product, make the device useful for multi-throw switch and switched phase shifter circuits requiring < 40 nS switching speeds up to 18 GHz operating frequency

# Absolute Maximum Ratings @ 25 °C<sup>1</sup>

Parameter	Value		
Forward Current	100 mA		
Reverse Voltage	-100 V		
Operating Temperature	-55 °C to +150 °C		
Storage Temperature	-55 °C to +150 °C		
Junction Temperature	+175 °C		
Dissipated Power	150 mW		
Mounting Temperature	+300 °C for 10 seconds		

 Exceeding any of these values may result in permanent damage

### 1269 Outline Drawing



### **Nominal Die Dimensions**

	Inches		Millimeters		
Dim	Min	Max	Min	Max	
Α	0.0269	0.0289	0.683	0.733	
В	0.0135	0.0155	0.343	0.393	
С	0.0040	0.0080	0.102	0.203	
D	0.0041	0.0061	0.105	0.155	
Е	0.0124	0.0144	0.315	0.365	
F	0.0069	0.0089	0.175	0.225	

V 1.00

### Electrical Specifications @ $T_A = + 25$ °C

Parameters @ Conditions	Symbol	Units	Min.	Тур.	Max.
Total Capacitance @ -10 V, 1 MHz <sup>1</sup>	Ст	pF		0.045	0.050
Total Capacitance @ -10 V, 1 GHz <sup>1,3</sup>	Ст	pF		0.025	
Series Resistance @ +50 mA <sup>2,3</sup> , 100 MHz	Rs	Ω		2.1	
Series Resistance @ +50 mA <sup>2,3</sup> , 1 GHz	R <sub>s</sub>	Ω		2.6	
Forward Voltage @ +100 mA	V <sub>F</sub>	V		1.1	1.5
Reverse Voltage @ -10 μ A	V <sub>R</sub>	V	I -70 I	I -100 I	
Reverse Current @ -70 V	I <sub>R</sub>	nA		I -100 I	
50 - 90% Lifetime @ +10 mA / -6 mA	TL	ns		140	
Steady State Thermal Resistance <sup>4</sup>	θ	° C/W		450	

- 1. Total capacitance is equivalent to the sum of junction capacitance Cj and parasitic capacitance, Cp.
- 2. Series resistance R<sub>S</sub> is equivalent to the total diode series resistance including the junction resistance Rj.
- 3. Rs and Cp measured on an HP4291A with die mounted in an ODS-186 package.
- 4. Steady-state thermal resistance measured with die mounted in an ODS-186 package.

### **Assembly Considerations**

The following precautions should be observed for successful assembly of the die.

### **Cleanliness**

These chips should be handled in a clean environment. Do not attempt to clean die after installation.

### **ESD**

These devices very susceptible to ESD and are rated Class 0 (0-199 V) per HBM MIL-STD-883, method 3015.7 [C = 100 pF  $\pm$ 10%, R = 1.5k  $\Omega$   $\pm$ 1%]. Even though tested die pass 100 V ESD, they must be handled in a static-free environment

### **General Handling**

The protective polymer coating on the active areas of these devices provides scratch protection, particularly for the metal airbridge that contacts the anode. Die can be handled with tweezers or vacuum pickups and are suitable for use with automatic pick-and-place equipment.

# Solder Die Attach Using

These devices were designed for insertion onto hard or soft

substrates with the junction side down. They can be mounted with electrically conductive epoxy or with a low temperature solder preform. The die can also be assembled with the junction side up, and wire or ribbon bonds made to the pads.

## **Electrically Conductive Ag Epoxy** and **Solder**

**Mounting Techniques** 

These chips are designed to be inserted onto hard or soft substrates with the junction side down. They should be mounted onto silkscreened circuits using Electrically Conductive Ag Epoxy, approximately 1-2 mils in thickness and cured at approximately 90 °C to 150 °C per manufacturer's schedule . For extended cure times >30 minutes, temperatures must be below 200 °C.

Sn Rich Solders are not recommended due to the Tungsten Metallization scheme beneath the gold contacts. Indalloy or 80~Au/20~Sn Solders are acceptable. Maximum soldering temperature must be  $<300~^{\circ}C$  for <10~sec.

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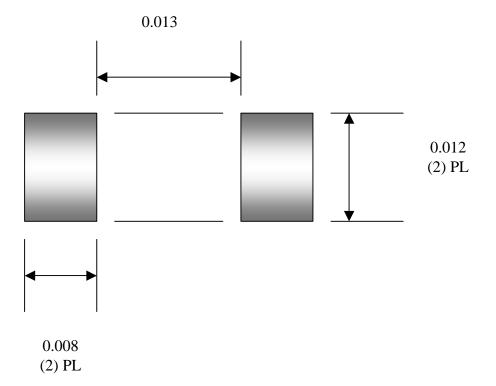
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V 1.00

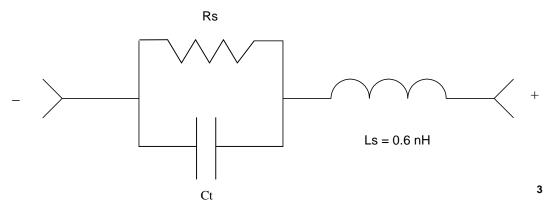
### **Circuit Mounting Dimensions (Inches)**



### **Ordering Information**

Part Number	Package
MA4FCP300	Die in Carrier
MA4FCP300-T	Tape/Reel
MA4FCP300-W	Wafer on Frame

### Diode Model



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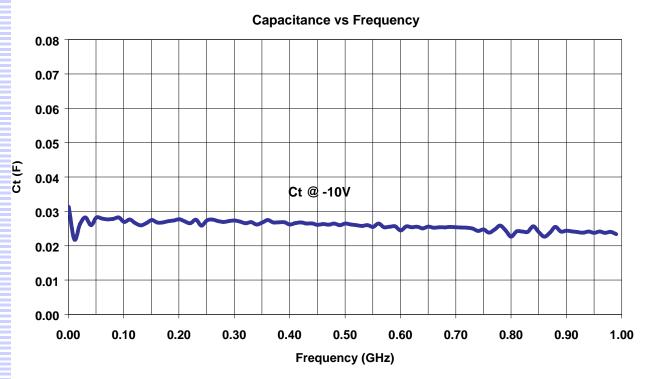
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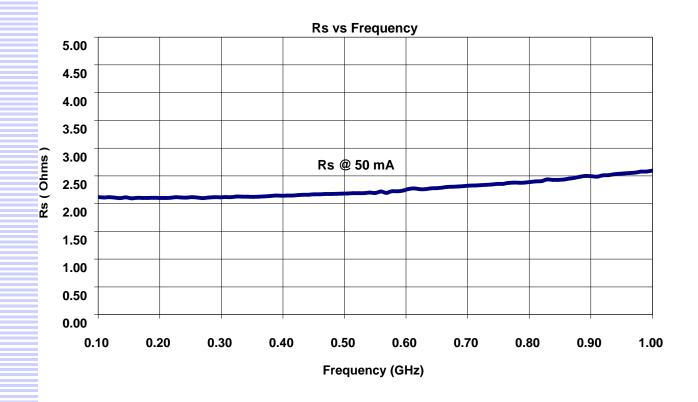
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